SENSITRON SEMICONDUCTOR

TECHNICAL DATA
DATA SHEET 209, REV A

HERMETIC ULTRAFAST RECOVERY RECTIFIER

DESCRIPTION: 100 VOLT, 40 AMP, 35 NANOSECOND, HERMETIC RECTIFIER IN A TO-254 PACKAGE.

MAX RATINGS/ELECTRICAL CHARACTERISTICS ALL RATINGS ARE AT T_A = 25 °C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE (PER LEG)	PIV	100	Volts
MAXIMUM FORWARD VOLTAGE DROP (PER LEG) (I_f = 10 Amps) I_F = 10A, T_A = 25 C° I_F = 10A,T_A = 125 C°	V_f	1.0 0.83	Volts
MAXIMUM DC OUTPUT CURRENT (T_C = 100 °C)	I_O	40	Amps
PEAK SINGLE CYCLE SURGE CURRENT t_p = 8.3 msec.	I_{FSM}	300	Amps
MAXIMUM REVERSE RECOVERY TIME (I_f = 0.5A, I_r = 1.0A, I_{rr} = 0.25A)	t_{rr}	35	nsec
MAXIMUM REVERSE CURRENT I_r @ PIV (PER LEG)	I_r	10 1.0	µA mA
MAXIMUM THERMAL RESISTANCE (PER LEG)	$R_{\theta JC}$	2.3	°C/W
MAXIMUM OPERATING TEMPERATURE RANGE	-	-65 to +200	°C
JUNCTION CAPACITANCE V_R = 10Vdc, f = 1mHz V_{SIG} = 50mV (p-p) (Max)	C_J	150	pF

* Suffix R denotes common anode version.

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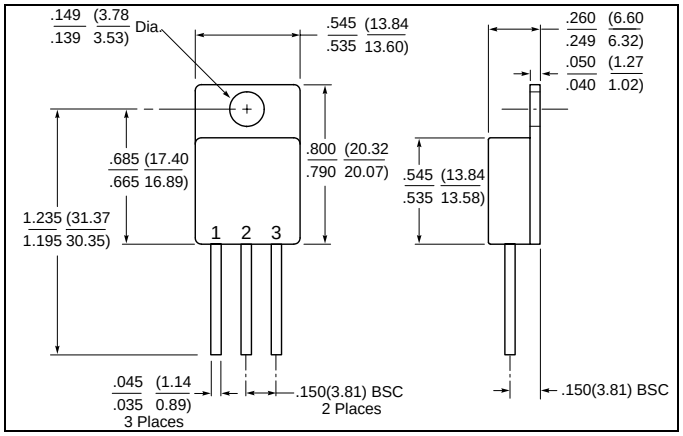
MECHANICAL DIMENSIONS: In Inches / mm

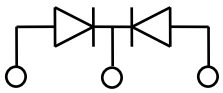


TO-254

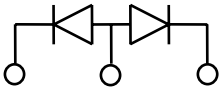
PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER, COMMON CATHODE	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (R)	CATHODE 1	COMMON ANODE	CATHODE 2

SCHEMATIC



COMMON CATHODE



COMMON ANODE

TECHNICAL DATA

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